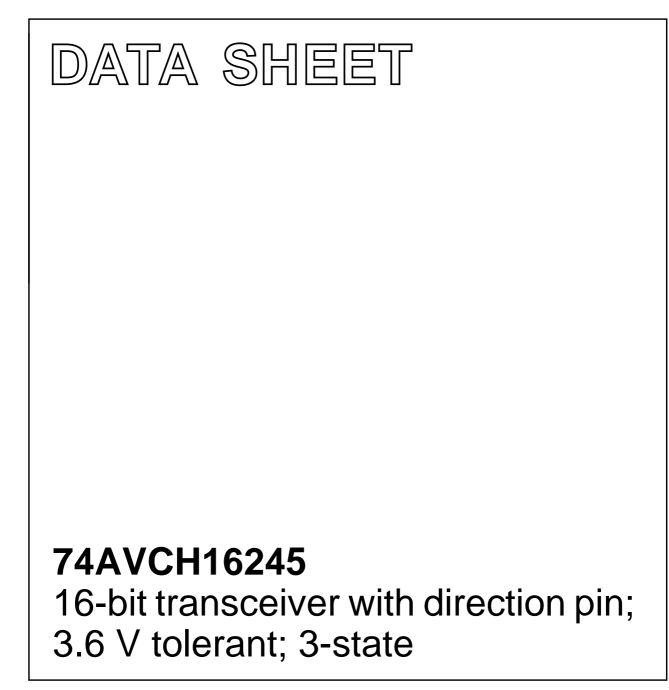
INTEGRATED CIRCUITS



Product Specification File under Integrated Circuits, IC24 2000 Mar 07



74AVCH16245

FEATURES

- Wide supply voltage range from 1.2 to 3.6 V
- Complies with JEDEC standard no. 8-1A/5/7
- CMOS low power consumption
- Input/output tolerant up to 3.6 V
- Dynamic Controlled Output (DCO) circuit dynamically changes output impedance, resulting in noise reduction without speed degradation
- Low inductance multiple V_{CC} and GND pins to minimize noise and ground bounce
- Supports Live Insertion
- All inputs have bus-hold.

DESCRIPTION

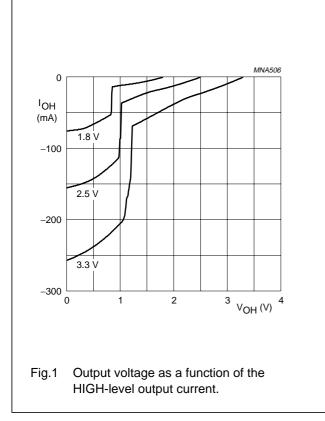
The 74AVCH16245 is a 16-bit transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The device features two output enable inputs ($n\overline{OE}$) for easy cascading and two send/receive inputs (nDIR) for direction control. Inputs $n\overline{OE}$ control the outputs so that the buses are effectively isolated. This device can be used as two 8-bit transceivers or one 16-bit transceiver.

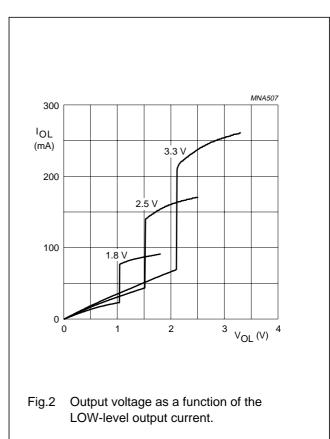
The 74AVCH16245 is designed to have an extremely fast propagation delay and a minimum amount of power consumption.

To ensure the high-impedance output state during power-up or power-down, pins $n\overline{OE}$ should be tied to V_{CC} through a pull-up resistor (Live Insertion).

A Dynamic Controlled Output (DCO) circuitry is implemented to support termination line drive during transient (see Figs 1 and 2).

The 74AVCH16245 has active bus-hold circuitry to hold unused or floating data inputs at a valid logic level. This feature eliminates the need for external pull-up or pull-down resistors.





74AVCH16245

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25 \text{ °C}$; $t_r = t_f \le 2.0 \text{ ns.}$

SYMBOL	PARAMETER	CONDITIONS	TYP.	UNIT
t _{PHL} /t _{PLH}	propagation delay nA _n to nB _n ;	V _{CC} = 1.2 V	5.4	ns
	nB _n to nA _n	V _{CC} = 1.5 V	3.1	ns
		V _{CC} = 1.8 V	2.3	ns
		V _{CC} = 2.5 V	1.6	ns
		V _{CC} = 3.3 V	1.4	ns
CI	input capacitance		5.0	pF
C _{PD}	power dissipation capacitance per	notes 1 and 2		
	buffer	outputs enabled	42	pF
		outputs disabled	2	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

2. The condition is $V_I = GND$ to V_{CC} .

FUNCTION TABLE

See note 1.

INP	UTS	INPUTS/OUTPUTS		
nOE	nDIR	nA _n	nB _n	
L	L	A = B	inputs	
L	Н	inputs	B = A	
Н	Х	Z	Z	

Note

1. H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

Z = high impedance OFF-state.

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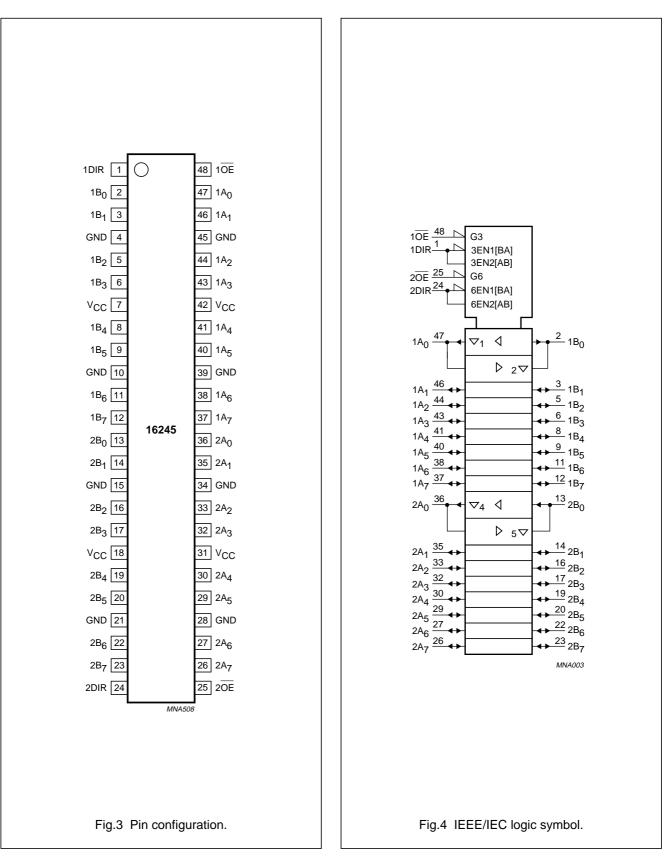
ORDERING AND PACKAGE INFORMATION

TYPE NUMBER	PACKAGE						
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE		
74AVC16245DGG	–40 to +85 °C	48	TSSOP	plastic	SOT362-1		

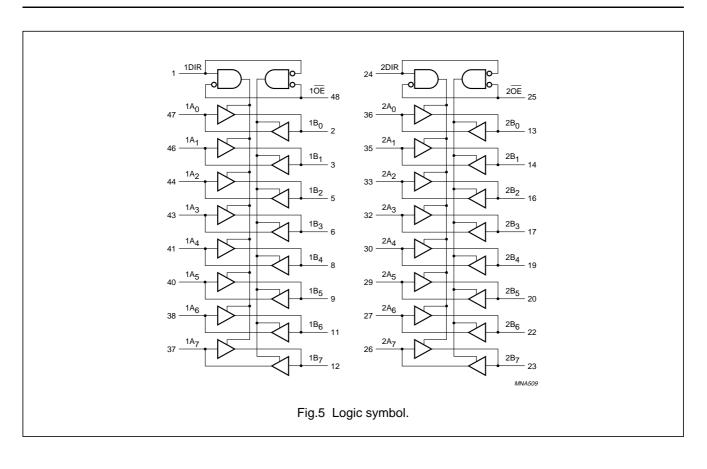
PINNING

PIN	SYMBOL	DESCRIPTION
1	1DIR	direction control
2, 3, 5, 6, 8, 9, 11 and 12	1B ₀ to 1B ₇	data inputs/outputs
4, 10, 15, 21, 28, 34, 39 and 45	GND	ground (0 V)
7, 18, 31 and 42	V _{CC}	DC supply voltage
13, 14, 16, 17, 19, 20, 22 and 23	2B ₀ to 2B ₇	data inputs/outputs
24	2DIR	direction control
25	2 0E	output enable input (active LOW)
26, 27, 29, 30, 32, 33, 35 and 36	2A ₇ to 2A ₀	data inputs/outputs
37, 38, 40, 41, 43, 44, 46 and 47	1A ₇ to 1A ₀	data inputs/outputs
48	1 0E	output enable input (active LOW)

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	DC supply voltage	according to JEDEC Low Voltage	1.4	1.6	V
		Standards	1.65	1.95	V
			2.3	2.7	V
			3.0	3.6	V
		for low-voltage applications	1.2	3.6	V
VI	DC input voltage		0	3.6	V
Vo	DC output voltage	output 3-state	0	3.6	V
		output HIGH or LOW state	0	V _{CC}	V
T _{amb}	operating ambient temperature	in free air	-40	+85	°C
t _r , t _f	input rise and fall ratios	V _{CC} = 1.4 to 1.6 V	0	40	ns/V
		V _{CC} = 1.65 to 2.3 V	0	30	ns/V
		V _{CC} = 2.3 to 3.0 V	0	20	ns/V
		V _{CC} = 3.0 to 3.6 V	0	10	ns/V

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	DC supply voltage		-0.5	+4.6	V
I _{IK}	DC input diode current	V _I < 0	-	-50	mA
VI	DC input voltage	for inputs; note 1	-0.5	+4.6	V
I _{ОК}	DC output clamping diode current	V _O < 0	-	-50	mA
Vo	DC output voltage	output HIGH or LOW state; note 1	-0.5	V _{CC} + 0.5	V
		output 3-state; note 1	-0.5	+4.6	V
lo	DC output sink current	$V_{O} = 0$ to V_{CC}	-	50	mA
I _{CC} , I _{GND}	DC V _{CC} or GND current		-	±100	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	power dissipation per package	for temperature range: –40 to +85 °C; note 2	_	500	mW

Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. Above 60 $^\circ\text{C}$ the value of P_D derates linearly with 5.5 mW/K.

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DC CHARACTERISTICS

Over recommended operating conditions; voltages are referenced to GND (ground = 0 V).

		TEST CONDITIONS		T _{am}			
SYMBOL	PARAMETER	OTHER	V _{CC} (V)	MIN.	TYP. ⁽¹⁾	MAX.	
VIH	HIGH-level input		1.2	V _{CC}	-	-	V
	voltage		1.4 to 1.6	$0.65 \times V_{CC}$	0.9	_	V
			1.65 to 1.95	$0.65 \times V_{CC}$	0.9	_	V
			2.3 to 2.7	1.7	1.2	_	V
			3.0 to 3.6	2.0	1.5	_	V
V _{IL}	LOW-level input		1.2	-	_	GND	V
	voltage		1.4 to 1.6	_	0.9	$0.35 \times V_{CC}$	V
			1.65 to 1.95	_	0.9	$0.35 \times V_{CC}$	V
			2.3 to 2.7	_	1.2	0.7	V
			3.0 to 3.6	_	1.5	0.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$					
	voltage	$I_{O} = -100 \mu A$	1.65 to 3.6	V _{CC} – 0.20	V _{CC}	_	V
		$I_0 = -3 \text{ mA}$	1.4	V _{CC} – 0.35	V _{CC} – 0.21	_	V
		$I_0 = -4 \text{ mA}$	1.65	V _{CC} – 0.45	V _{CC} – 0.25		V
		$I_0 = -8 \text{ mA}$	2.3	V _{CC} – 0.55	V _{CC} – 0.37		V
		$I_0 = -12 \text{ mA}$	3.0	V _{CC} – 0.70	V _{CC} - 0.47		V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$					<u> </u>
02	voltage	$I_{O} = 100 \mu A$	1.65 to 3.6	_	GND	0.20	V
		$I_0 = 3 \text{ mA}$	1.4	_	0.22	0.35	V
		$I_0 = 4 \text{ mA}$	1.65	_	0.24	0.45	V
		I _O = 8 mA	2.3	_	0.38	0.55	V
		I _O = 12 mA	3.0	_	0.53	0.70	V
I	input leakage current	$V_{I} = V_{CC}$ or GND	1.4 to 3.6	-	0.1	2.5	μA
l _{off}	power-off leakage current	$V_{\rm I}$ or $V_{\rm O}$ = 3.6 V	0	-	0.1	±10	μA
I _{IHZ} /I _{ILZ}	input current for common I/O pins	$V_{I} = V_{CC}$ or GND	1.4 to 3.6	-	0.1	12.5	μA
I _{OZ}	3-state output	$V_I = V_{IH} \text{ or } V_{IL};$	1.4 to 2.7	-	0.1	5	μA
	OFF-state current	$V_{O} = V_{CC}$ or GND	3.0 to 3.6	-	0.1	10	μA
I _{CC}	quiescent supply	$V_I = V_{CC}$ or GND;	1.4 to 2.7	-	0.1	20	μA
	current	I _O = 0	3.0 to 3.6	-	0.2	40	μA
I _{BHL}	bus-hold LOW	$V_{I} = 0.35 \times V_{CC}$	1.65	25	-	_	μA
	sustaining current	V _I = 0.7 V	2.3	45	-	-	μA
		V _I = 0.8 V	3.0	75	-	_	μA
I _{BHH}	bus-hold HIGH	$V_{I} = 0.65 \times V_{CC}$	1.65	-25	-	_	μA
	sustaining current		2.3	-45	-	_	μA
			3.0	-75	_	_	μA

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SYMBOL		TEST CONDITIONS		T _{amb} = −40 to +85 °C			
	PARAMETER	OTHER	V _{CC} (V)	MIN.	TYP. ⁽¹⁾	MAX.	
I _{BHLO}	bus-hold LOW		1.95	200	_	-	μA
	overdrive current		2.7	300	_	-	μA
			3.6	450	_	-	μA
I _{BHHO}	bus-hold HIGH		1.95	-200	-	-	μA
0	overdrive current		2.7	-300	_	-	μA
			3.6	-450	_	-	μA

Note

1. All typical values are measured at T_{amb} = 25 °C.

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AC CHARACTERISTICS

 $GND = 0 V; t_r = t_f \le 2.0 ns.$

SYMBOL		TEST CONE	T_{amb} = -40 to +85 °C				
STNIDUL	PARAMETER	WAVEFORMS	V _{CC} (V)	MIN.	TYP. ⁽¹⁾	MAX.	UNIT
t _{PHL} /t _{PLH}	propagation delay; nA _n to nB _n ;	see Figs 6 and 8	1.2	-	5.4	-	ns
	nB _n to nA _n		1.40 to 1.60	_	3.1	_	ns
			1.65 to 1.95	1.4	2.3	3.3	ns
			2.3 to 2.7	0.5	1.6	2.2	ns
			3.0 to 3.6	0.7	1.4	2.0	ns
t _{PZH} /t _{PZL}	3-state output enable time;	see Figs 7 and 8	1.2	_	7.4	_	ns
	$n\overline{OE}$ to nA_n ; $n\overline{OE}$ to nB_n	to nB _n	1.40 to 1.60	_	6.4	_	ns
			1.65 to 1.95	1.4	4.4	7.0	ns
			2.3 to 2.7	1.0	2.8	4.3	ns
			3.0 to 3.6	0.7	2.3	3.7	ns
t _{PHZ} /t _{PLZ}	3-state output disable time;	see Figs 7 and 8	1.2	-	7.3	-	ns
	$n\overline{OE}$ to nA_n ; $n\overline{OE}$ to nB_n		1.40 to 1.60	_	5.7	_	ns
			1.65 to 1.95	2.2	4.2	7.0	ns
			2.3 to 2.7	1.1	2.3	5.4	ns
			3.0 to 3.6	1.2	2.5	3.9	ns

Note

1. All typical values are measured at T_{amb} = 25 °C and at V_{CC} respectively 1.2, 1.5, 1.8, 2.5 and 3.3 V.

AC WAVEFORMS

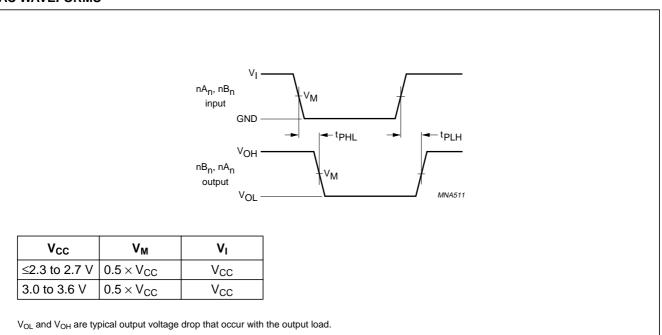


Fig.6 The input (nA_n, nB_n) to output (nB_n, nA_n) propagation delay.

74AVCH16245

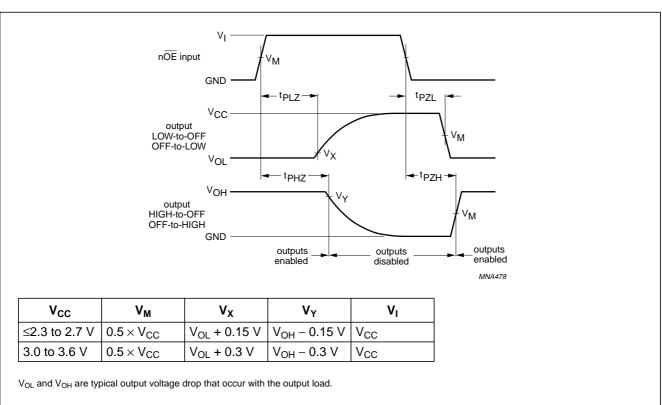
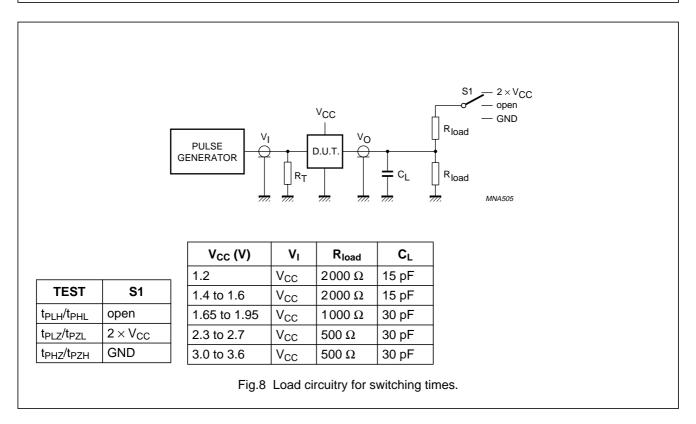


Fig.7 The 3-state enable and disable times.



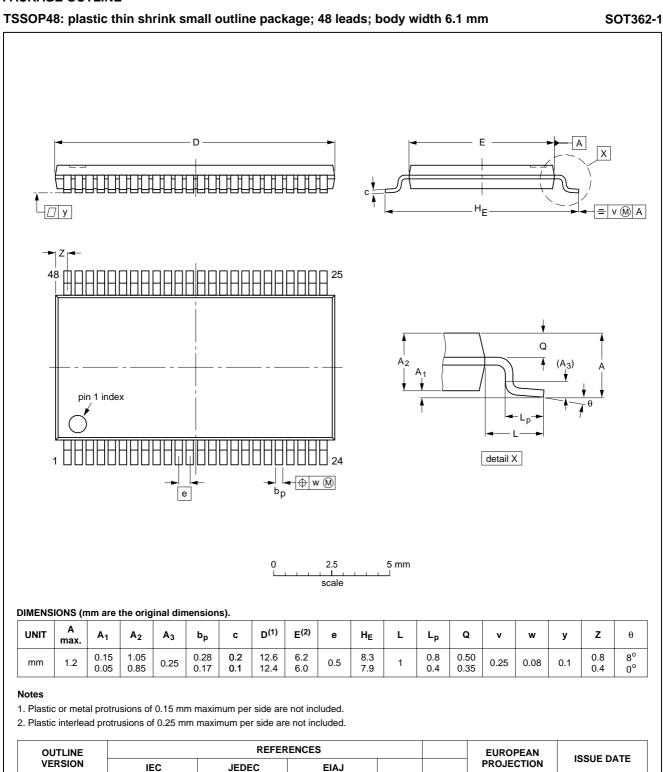
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74AVCH16245

16-bit transceiver with direction pin; 3.6 V tolerant; 3-state

PACKAGE OUTLINE



SOT362-1

MO-153

74AVCH16245

SOLDERING

Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering is not always suitable for surface mount ICs, or for printed-circuit boards with high population densities. In these situations reflow soldering is often used.

Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, infrared/convection heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferable be kept below 230 °C.

Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

• For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C. A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 $^\circ\text{C}.$

74AVCH16245

Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE	SOLDERING METHOD		
FACKAGE	WAVE	REFLOW ⁽¹⁾	
BGA, LFBGA, SQFP, TFBGA	not suitable	suitable	
HBCC, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, SMS	not suitable ⁽²⁾	suitable	
PLCC ⁽³⁾ , SO, SOJ	suitable	suitable	
LQFP, QFP, TQFP	not recommended ⁽³⁾⁽⁴⁾	suitable	
SSOP, TSSOP, VSO	not recommended ⁽⁵⁾	suitable	

Notes

- 1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the "Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods".
- 2. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
- 3. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- 4. Wave soldering is only suitable for LQFP, TQFP and QFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- 5. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

16-bit transceiver with direction pin; 3.6 V tolerant;	7441/01/46045
3-state	74AVCH16245

NOTES

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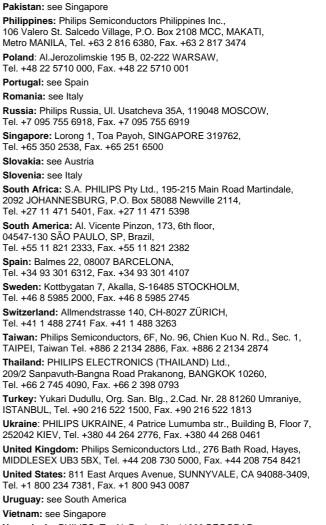
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